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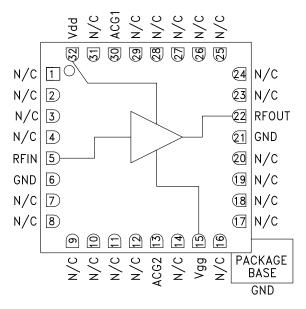


#### **Typical Applications**

The HMC460LC5 is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation

#### **Functional Diagram**



## HMC460LC5

#### GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

#### Features

Noise Figure: 2.5 dB @ 10 GHz Gain: 14 dB @ 10 GHz P1dB Output Power: +16.5 dBm @ 10 GHz Supply Voltage: +8V @ 75 mA 50 Ohm Matched Input/Output 32 Lead Ceramic 5x5mm SMT Package: 25mm<sup>2</sup>

#### **General Description**

The HMC460LC5 is a GaAs MMIC pHEMT Low Noise Distributed Amplifier in a leadless 5x5 mm ceramic surface mount package which operates from DC to 20 GHz. The amplifier provides 14 dB of gain, 2.5 dB noise figure and +16.5 dBm of output power at 1 dB gain compression while requiring only 75 mA from a Vdd = 8V supply. Gain flatness is excellent from DC to 20 GHz making the HMC460LC5 ideal for EW, ECM, Radar and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms.

#### Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd= 8V, Idd= 75 mA\*

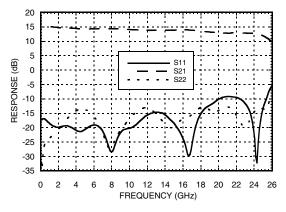
| Parameter  | Min.     | Тур.  | Max.       | Min. | Тур.        | Max. | Min. | Тур.   | Max. | Units  |
|--|----------|-------|------------|------|-------------|------|------|--------|------|--------|
| Frequency Range                                    | DC - 6.0 |       | 6.0 - 18.0 |      | 18.0 - 20.0 |      |      | GHz    |      |        |
| Gain   | 11       | 14    |            | 11   | 14          |      | 10   | 13     |      | dB     |
| Gain Flatness                                      |          | ± 0.5 |            |      | ± 0.15      |      |      | ± 0.25 |      | dB     |
| Gain Variation Over Temperature                    |          | 0.008 |            |      | 0.01        |      |      | 0.01   |      | dB/ °C |
| Noise Figure                                       |          | 3.5   | 5.0        |      | 2.5         | 4.0  |      | 3.5    | 5    | dB     |
| Input Return Loss                                  |          | 17    |            |      | 18          |      |      | 12     |      | dB     |
| Output Return Loss                                 |          | 17    |            |      | 15          |      |      | 15     |      | dB     |
| Output Power for 1 dB Compression (P1dB)           | 14       | 17    |            | 13   | 16          |      | 12   | 15     |      | dBm    |
| Saturated Output Power (Psat)                      |          | 18    |            |      | 18          |      |      | 17     |      | dBm    |
| Output Third Order Intercept (IP3)                 |          | 29.5  |            |      | 29          |      |      | 28.5   |      | dBm    |
| Supply Current<br>(Idd) (Vdd= 8V, Vgg= -0.9V Typ.) |          | 75    |            |      | 75          |      |      | 75     |      | mA     |

\* Adjust Vgg between -2 to 0V to achieve Idd= 75 mA typical.

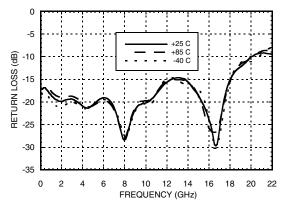


## ROHSV EARTH FRIEND

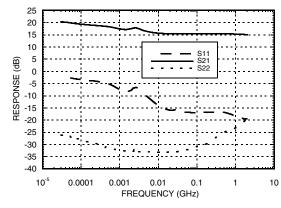
#### Broadband Gain & Return Loss



Input Return Loss vs. Temperature



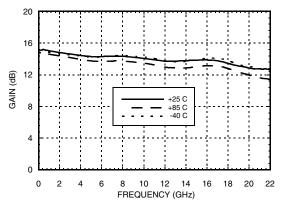
Low Frequency Gain & Return Loss



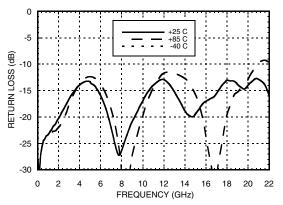
#### GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

HMC460LC5

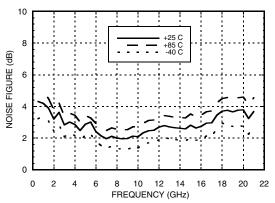
#### Gain vs. Temperature



#### Output Return Loss vs. Temperature



Noise Figure vs. Temperature

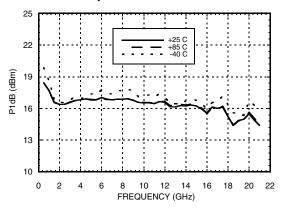




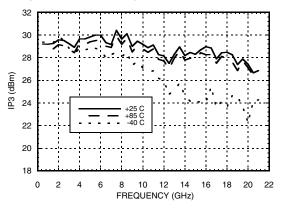


## ROHS EARTH FRIENDL

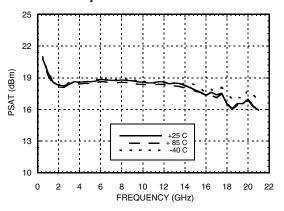
#### P1dB vs. Temperature



Output IP3 vs. Temperature



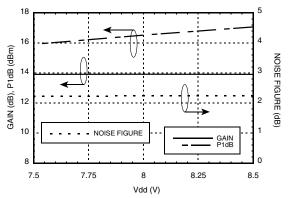
Psat vs. Temperature

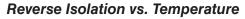


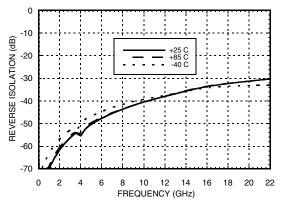
GaAs pHEMT MMIC LOW NOISE

AMPLIFIER, DC - 20 GHz

Gain, Power & Noise Figure vs. Supply Voltage @ 10 GHz, Fixed Vgg











#### GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

#### Absolute Maximum Ratings

| Drain Bias Voltage (Vdd)                                      | +9 Vdc         |
|---|----------------|
| Gate Bias Voltage (Vgg)                                       | -2 to 0 Vdc    |
| Gate Bias Voltage (Igg)                                       | 2.5 mA         |
| RF Input Power (RFIN)(Vdd = +8 Vdc)                           | +18 dBm        |
| Channel Temperature   | 175 °C         |
| Continuous Pdiss (T = 85 °C)<br>(derate 23 mW/°C above 85 °C) | 2 W            |
| Thermal Resistance<br>(channel to package bottom)             | 44.4 °C/W      |
| Storage Temperature   | -65 to +150 °C |
| Operating Temperature   | -55 to +85 °C  |

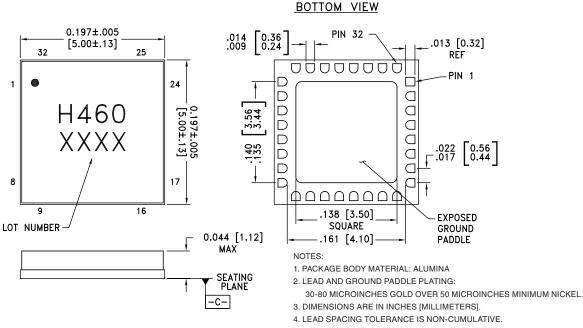
#### Typical Supply Current vs. Vdd

| Vdd (V) | ldd (mA) |
|---------|----------|
| +7.5    | 74       |
| +8.0    | 75       |
| +8.5    | 76       |



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

#### **Outline Drawing**



5 PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-

6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

#### **Package Information**

| Part Number | Package Body Material | Lead Finish      | MSL Rating          | Package Marking <sup>[2]</sup> |  |
|-------------|-----------------------|------------------|---------------------|--------------------------------|--|
| HMC460LC5   | Alumina, White        | Gold over Nickel | MSL3 <sup>[1]</sup> | H460<br>XXXX                   |  |

[1] Max peak reflow temperature of 260  $^\circ\text{C}$ 

[2] 4-Digit lot number XXXX





#### GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

#### **Pin Descriptions**

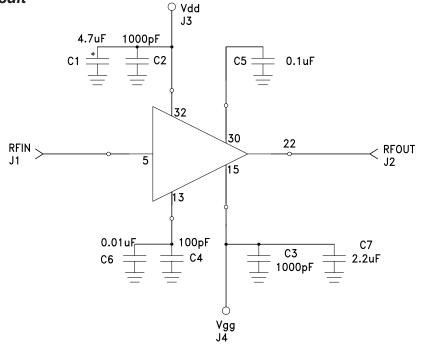
| Pin Number                                    | Function | Description  | Interface Schematic       |
|---|----------|--|---------------------------|
| 1 - 4, 7 - 12,<br>14, 16 - 20,<br>23 - 29, 31 | N/C      | No connection. These pins may be connected to RF ground.<br>Performance will not be affected.      |                           |
| 5   | RFIN     | This pin is DC coupled and matched to 50 Ohms.   | RFIN ACG2                 |
| 6, 21   | GND      | Package bottom must be connected to RF/DC ground.  |                           |
| 13  | ACG2     | Low frequency termination. Attach bypass capacitor per application circuit herein.                 | RFIN ACG2                 |
| 15  | Vgg      | Gate control for amplifier.<br>Please follow"MMIC Amplifier Biasing Procedure"<br>application note | VggO                      |
| 22  | RFOUT    | This pin is DC coupled and matched to 50 Ohms.   | O RFOUT                   |
| 30  | ACG1     | Low frequency termination. Attach bypass capacitor per application circuit herein.                 |                           |
| 32  | Vdd      | Power supply voltage for the amplifier.<br>External bypass capacitors are required                 | <br>↓<br>↓<br>↓<br>↓<br>↓ |



#### GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz

# 

#### **Application Circuit**



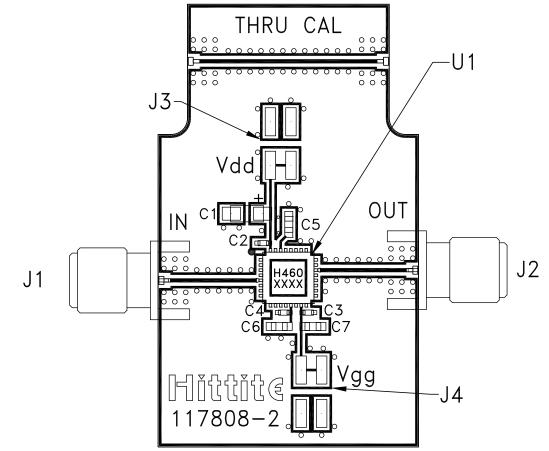




#### GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz



#### **Evaluation PCB**



#### List of Materials for Evaluation PCB 117810 [1]

| Γ       |                              |
|---------|------------------------------|
| Item    | Description                  |
| J1 - J2 | PCB Mount SMA Connector      |
| J3 - J4 | 2 mm Molex Header            |
| C4      | 100 pF Capacitor, 0402 Pkg.  |
| C2, C3  | 1000 pF Capacitor, 0402 Pkg. |
| C1      | 4.7 µF Capacitor, Tantalum   |
| C5      | 0.1 uF Capacitor, 0603 Pkg.  |
| C6      | 0.01 uF Capacitor, 0603 Pkg. |
| C7      | 2.2 uF Capacitor, 0603 Pkg.  |
| U1      | HMC460LC5                    |
| PCB [2] | 117808 Evaluation PCB        |
|         |                              |

Reference this number when ordering complete evaluation PCB
 Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

 List of Materia

 Item

 J1 - J2

 J3 - J4

 C4

 C2, C3

 C1

 C5

 C6





#### GaAs pHEMT MMIC LOW NOISE AMPLIFIER, DC - 20 GHz